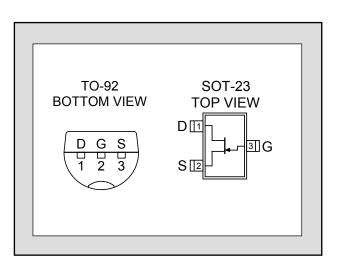
## INEAR SYSTEMS

### Linear Integrated Systems

FEATURES					
ULTRA LOW NOISE (f = 1kHz)	e <sub>n</sub> = 0.9nV/√Hz				
HIGH BREAKDOWN VOLTAGE	$BV_{GSS}$ = 40V max				
HIGH GAIN	Y <sub>fs</sub> = 22mS (typ)				
HIGH INPUT IMPEDANCE	$I_G$ = -500pA max				
LOW CAPACITANCE	22pF max				
IMPROVED SECOND SOURCE REPLACEMENT FOR 2SK170					
ABSOLUTE MAXIMUM RATINGS <sup>1</sup>					
@ 25 °C (unless otherwise stated)					
Maximum Temperatures					
Storage Temperature	-65 to +150 °C				
Operating Junction Temperature	-55 to +135 °C				
Maximum Power Dissipation					
Continuous Power Dissipation @ +125 °C	400mW				
Maximum Currents					
Gate Forward Current	$I_{G(F)} = 10 \text{mA}$				
Maximum Voltages					
Gate to Source	$V_{GSS} = 40V$				
Gate to Drain	$V_{GDS}$ = 40V				

# LSK170

## ULTRA LOW NOISE SINGLE N-CHANNEL JFET



\*For equivalent monolithic dual, see LSK389 family.

#### ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC		MIN	TYP	MAX	UNITS	CONDITIONS	
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage		40			V	V <sub>DS</sub> = 0, I <sub>D</sub> = 100µA	
$V_{GS(OFF)}$	Gate to Source Pinch-off Voltage		0.2		2	V	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1nA	
V <sub>GS</sub>	Gate to Source Operating Voltage			0.5		V	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	
I <sub>DSS</sub>	Drain to Source Saturation	LSK170A	2.6		6.5	mA	V <sub>DG</sub> = 10V, V <sub>GS</sub> = 0	
		LSK170B	6		12			
		LSK170C	10		20			
l <sub>G</sub>	Gate Operating Current				0.5	nA	$V_{DG} = 10V, I_{D} = 1mA$	
I <sub>GSS</sub>	Gate to Source Leakage Current				1	nA	V <sub>DG</sub> = 10V, V <sub>DS</sub> = 0	
Y <sub>fss</sub>	Full Conduction Transconductance			22		mS	$V_{GD}$ = 10V, $V_{GS}$ = 0, <i>f</i> = 1kHz	
Y <sub>fs</sub>	Typical Conduction Transconductance			10		mS	$V_{DG} = 15V, I_{D} = 1mA$	
en	Noise Voltage			0.9	1.9	nV/√Hz	$V_{DS}$ = 10V, $I_D$ = 2mA, $f$ = 1kHz, NBW = 1Hz	
en	Noise Voltage			2.5	4	nV/√Hz	$V_{DS} = 10V$ , $I_D = 2mA$ , $f = 10Hz$ , NBW = 1Hz	
CISS	Common Source Input Capacitance			20		pF	1/2 = 151/1 = 50000	
C <sub>RSS</sub>	Common Source Reverse Transfer Cap.			5		pF	V <sub>DS</sub> = 15V, I <sub>D</sub> = 500μA	

1. Absolute maximum ratings are limiting values above which serviceability may be impaired.

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